VS-HFA04SD60SHM3

Vishay Semiconductors

HEXFRED[®], Ultrafast Soft Recovery Diode, 4 A

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PRIMARY CHARACTERISTICS					
I _{F(AV)}	4 A				
V _R	600 V				
V _F at I _F	1.4 V				
t _{rr} typ.	17 ns				
T _J max.	150 °C				
Package	DPAK (TO-252AA)				
Circuit configuration	Single				

FEATURES

- Ultrafast recovery time
- Ultrasoft recovery
- Very low I_{RRM}
- Very low Q_{rr} · Guaranteed avalanche
- Specified at operating temperature
- AEC-Q101 qualified
- Meets JESD 201 class 2 whisker test
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

BENEFITS

- Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- · Reduced parts count

DESCRIPTION / APPLICATIONS

These diodes are optimized to reduce losses and EMI / RFI in high frequency power conditioning systems. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for freewheeling, flyback, power converters, motor drives, and other applications where high speed and reduced switching losses are design requirements.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Cathode to anode voltage	V _{RRM}		600	V	
Maximum continuous forward current	I _{F(AV)}	T _C = 100 °C	4		
Single pulse forward current	I _{FSM}		25	А	
Repetitive peak forward current	I _{FRM}	T _C = 116 °C	16		
Maximum power dissipation	PD	T _C = 100 °C	10	W	
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +150	°C	



COMPLIANT

HALOGEN

FREE







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ELECTRICAL SPECIFICATIONS ($T_J = 25$ °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-	
		I _F = 4 A	-	1.5	1.8	V
Forward voltage V _F	I _F = 8 A	-	1.8	2.2		
occ ng. 1		I _F = 4 A, T _J = 125 °C	-	1.4	1.7	
Maximum reverse	1	$V_{R} = V_{R}$ rated	-	0.17	3.0	
leakage current	I _R	$T_J = 125 \text{ °C}, V_R = 0.8 \text{ x } V_R \text{ rated}$	-	44	300	μA
Junction capacitance	CT	V _R = 200 V	-	4	8	pF
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8.0	-	nH

DYNAMIC RECOVERY CHARACTERISTICS ($T_C = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1.0 \text{ A}, \ dI_F/dt = 200 \text{ A}$	A/μA, V _R = 30 V	-	17	-	ns	
Reverse recovery time	t _{rr}	T _J = 25 °C		-	28	42		
		T _J = 125 °C	l _F = 4 A dl _F /dt = 200 A/μs V _R = 200 V	-	38	57		
Deals receivers convert		T _J = 25 °C		-	2.9	5.2	A	
Peak recovery current	IRRM	T _J = 125 °C		-	3.7	6.7		
	0	T _J = 25 °C		-	40	60	nC	
Reverse recovery charge Q _{rr}	Qrr	T _J = 125 °C		-	70	105	nc	
Rate of fall of recovery current dl(re	dl _{(rec)M} /dt	T _J = 25 °C		-	280	-	A/µs	
		T _J = 125 °C		-	235	-		

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	150	°C
Thermal resistance, junction to case	R _{thJC}		-	-	5.0	°C/W
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	80	0/10
Weight			-	2.0	-	g
Weight			-	0.07	-	oz.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style DPAK (TO-252AA)		HFA048	SD60SH	



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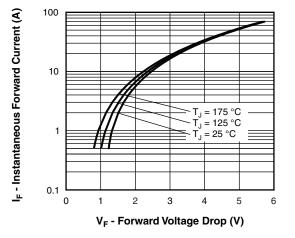


Fig. 1 - Typical Forward Voltage Drop Characteristics

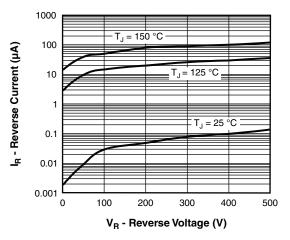


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

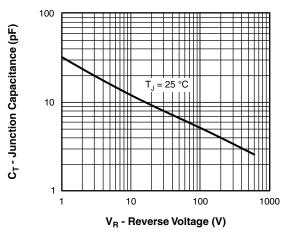


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

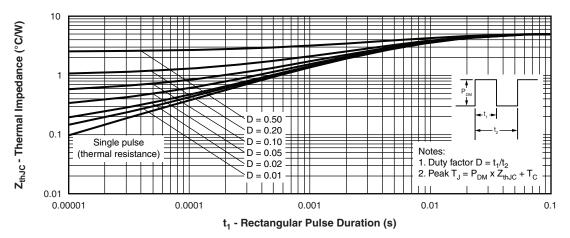


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

 Revision: 07-Jun-2023
 3
 Document Number: 94756

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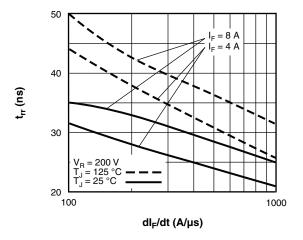
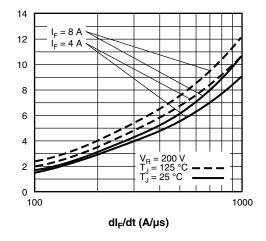


Fig. 5 - Typical Reverse Recovery Time vs. dI_F/dt



I_{RR} (A)

Fig. 6 - Typical Recovery Current vs. dl_F/dt

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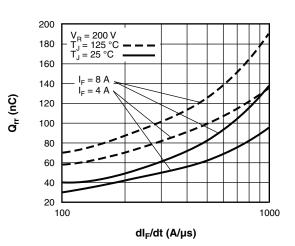
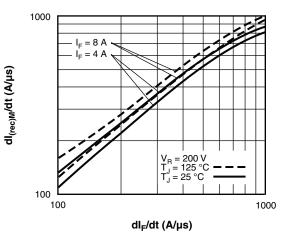


Fig. 7 - Typical Stored Charge vs. dl_F/dt





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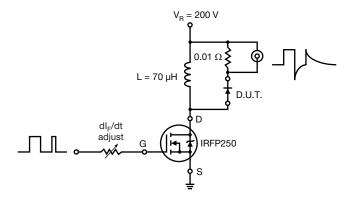


Fig. 9 - Reverse Recovery Parameter Test Circuit

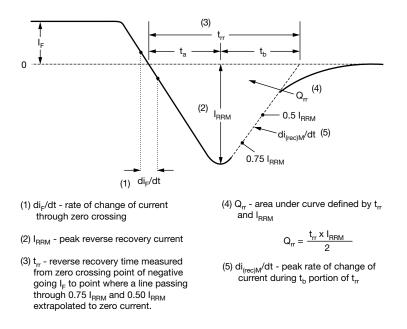


Fig. 10 - Reverse Recovery Waveform and Definitions

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ORDERING INFORMATION TABLE

Device code	vs-	HF	А	04	SD	60	S	TR	н	М3
		2	3	4	5	6	7	8	9	10
	1 -	- Vish	ay Sem	iconduc	tors pro	duct				
	2 -	HEX	(FRED [®]	family						
	3 -	Elec	Electron irradiated							
	4 -	Curr	Current rating $(04 = 4 \text{ A})$							
	5 -	D-P	D-PAK							
	6 -	Volta	Voltage rating (60 = 600 V)							
	7 -	S =	S = D-PAK							
	8 -	• TR	• TR = tape and reel							
		• R =	 R = tape and reel (right oriented) 							
	_	• L =	= tape ai	nd reel (left orie	nted)				
	9 -	H =	AEC-Q	101 qua	lified					
	10 -	Env	ironmer	ntal digit	:					
		M3	= halog	en-free,	RoHS-o	complia	nt, and	termina	tions lea	d (Pb)-fi

ORDERING INFORMATION (Example)						
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION				
VS-HFA04SD60SHM3	75	Antistatic plastic tube				
VS-HFA04SD60STRHM3	2000	13" diameter reel				
VS-HFA04SD60STRRHM3	3000	13" diameter reel				
VS-HFA04SD60STRLHM3	3000	13" diameter reel				

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95519					
Part marking information	www.vishay.com/doc?95518					
Packaging information	www.vishay.com/doc?95033					





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Revision: 01-Jan-2024